NSN 5961-01-376-2082

Diode Semiconductor Device - Page 1 of 1



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nclosure Material:
Glass or plastic or ceramic
Overall Length:
Between 0.140 inches and 0.195 inches
Terminal Length:
Between 0.900 inches and 1.300 inches
Overall Diameter:
Between 0.135 inches and 0.185 inches
Mounting Method:
Terminal
Features Provided:
Burn in
Cubic Measure:
0.020 cubic inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
28.0 breakdown voltage, dc
Voltage Tolerance In Percent:
5.0/+5.0
Current Rating Per Characteristic:
400.00 microamperes forward current, average peak
Power Rating Per Characteristic:
500.0 watts any acceptable preset
Test Data Document:
31349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
31349-mil-s-19500/516 government specification
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Filg:
A110a0